



	<b>Experiment title:</b> <b>Influence of crystal orientation relationships on the morphology of lamellar eutectic microstructures</b>	<b>Experiment number:</b> 32 02 812
<b>Beamline:</b> BM32	<b>Date of experiment:</b> from: June 28. 2018 to: July 2. 2018	<b>Date of report:</b> July 17, 2018
<b>Shifts:</b> 12	<b>Local contact(s):</b> Jean-Sébastien Micha	<i>Received at ESRF:</i>
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## Report:

### - Objective & expected results: -

The aim of this project (Proposal number: 20171113 ; Experiment number: 3202812) is to establish a link between microstructural features of melt-grown metallic composites and the orientation of the co-growing crystals. This is key to improving our understanding of the formation of textures in eutectic materials. Fundamentally, the challenge is to develop theoretical tools for predicting the self-organizing growth dynamics of eutectics and the anisotropy of the interphase boundaries in the solid. In practice, micro-diffraction analyses at BM32 (J.-S. Micha) aim at determining the crystal orientation relationships (ORs) between neighbouring crystals of the two eutectic-solid phases [the cubic Al-rich terminal solution (Al), and the tetragonal intermetallic Al<sub>2</sub>Cu] on a local scale in eutectic solidification microstructures of thin Al-Al<sub>2</sub>Cu metallic films. Synchrotron radiation permits to make non-destructive measurements through a sapphire-plate substrate.

### - Results and the conclusions of the study: -

Thin Al-Al<sub>2</sub>Cu films (thickness  $\approx$  9–14  $\mu\text{m}$ ; lateral dimensions  $8 \times 50 \text{ mm}^2$ ) are enclosed between two single-crystal sapphire (Al<sub>2</sub>O<sub>3</sub>) plates. They were prepared by plasma sputtering and solidified at INSP. The thickness of one sapphire plate was reduced to 200  $\mu\text{m}$ . Two solidification methods with real-time optical observation were employed: (i) directional solidification, and (ii) rotating directional solidification (RDS) that permits to vary continuously the orientation of the solid with respect to the growth axis.

We selected samples containing typically 2–4 lamellar-eutectic grains (each being supposedly uniform as regards the orientation of the crystals) of a few mm each. Non-destructive Laue micro-diffraction allows one to map the orientation of the alternating (Al) and Al<sub>2</sub>Cu crystals over selected regions, with good transmitted signal through the 200- $\mu\text{m}$  thick Al<sub>2</sub>O<sub>3</sub> substrate, and an actual resolution much better than the size of the smaller crystals ( $\approx$  5  $\mu\text{m}$ ). This provides a means for distinguishing between different grains, and gaining information on the degree of mosaicity, if present, within a given grain.

Sample n°	Alloy	DS/RDS/NA	Sapphire cover	Scan names	Analysis date
Ech44	Al-Al <sub>2</sub> Cu	DS	Yes	ROI01-ROI08 (tests) ROI01, ROI08-ROI21	06/28/2018 06/29/2018
Ech45	Al-Al <sub>2</sub> Cu	DS	Yes	ROI01-ROI09 ; ROI20-ROI22	06/30/2018
Ech49	Al-Al <sub>2</sub> Cu	DS	Yes	ROI01-ROI15	07/01/2018
Ech19	Al-Al <sub>2</sub> Cu	DS	No	ROI01	06/30/2018
Ech28	Al-Al <sub>2</sub> Cu	DS	No	ROI01-ROI08 ROI21-ROI28	06/28/2018
Ech62	Al-Al <sub>2</sub> Cu	RDS	Yes	ROI01-ROI09	07/01/2018
Ech59	Al-Al <sub>2</sub> Cu	NA	No	ROI depot	07/01/2018
Ech710	In-In <sub>2</sub> Bi	DS	***	ROI01-ROI03	07/01/2018

Table 1: List of samples and scans. DS: directional solidification. RDS: rotating directional solidification. NA: as-deposited sample. Note that Ech710 was a thin solidified In-In<sub>2</sub>Bi eutectic. \*\*\*  $\approx 50\mu\text{m}$  glass.

Each Region of Interest (ROI) was scanned, and an x-ray detector used to collect a characteristic fluorescence of copper for revealing the microstructure of the actually scanned area (Fig. 1). The raw output data are a set of Laue patterns for each ROI. For each sample, we also measured a Laue pattern on a reference Ge crystal fixed on the sample surface for fine angle-scale calibration, and another one on the sapphire plates.

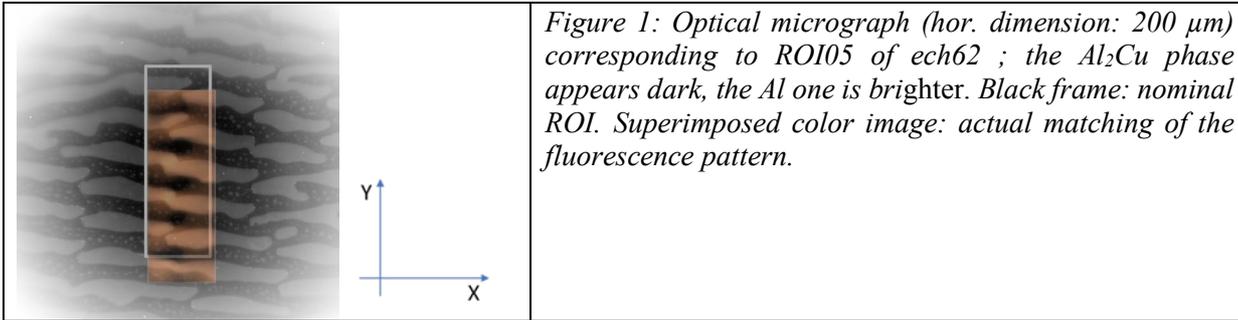


Figure 1: Optical micrograph (hor. dimension:  $200\mu\text{m}$ ) corresponding to ROI05 of ech62 ; the Al<sub>2</sub>Cu phase appears dark, the Al one is brighter. Black frame: nominal ROI. Superimposed color image: actual matching of the fluorescence pattern.

Let us now take Ech62 as an illustrative example (Fig. 2).

Fig. 3 shows a Laue pattern measured at some point in an Al lamella. Note that, in all Laue patterns, diffraction peaks coming from the Al<sub>2</sub>O<sub>3</sub> single-crystal substrates could be easily identified. Using the LaueTools software, we could locate Al peaks (see mosaic image, Fig. 3b), and successfully run a best-fit procedure (Fig. 3c). It is thus shown, in particular, that a (111) plane is tilted by a few degrees off the substrate. A similar analysis for a neighbouring Al<sub>2</sub>Cu lamella is shown in Fig. 4. We will extract the orientation of the crystals (rotation matrix and/or Euler angles), and look for special ORs.

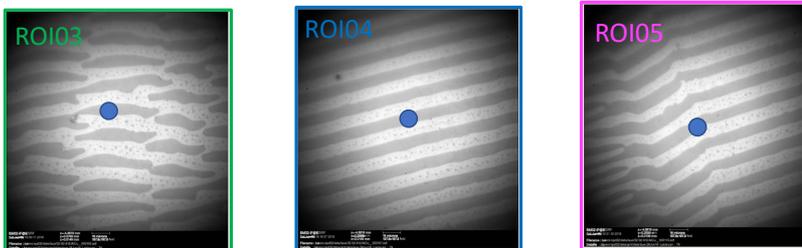


Figure 2: Sample Ech62: examples of ROIs (horizontal dimension:  $200\mu\text{m}$ ). The blue dot signals a given Al<sub>2</sub>Cu lamella that we followed over a long distance in the microstructure.

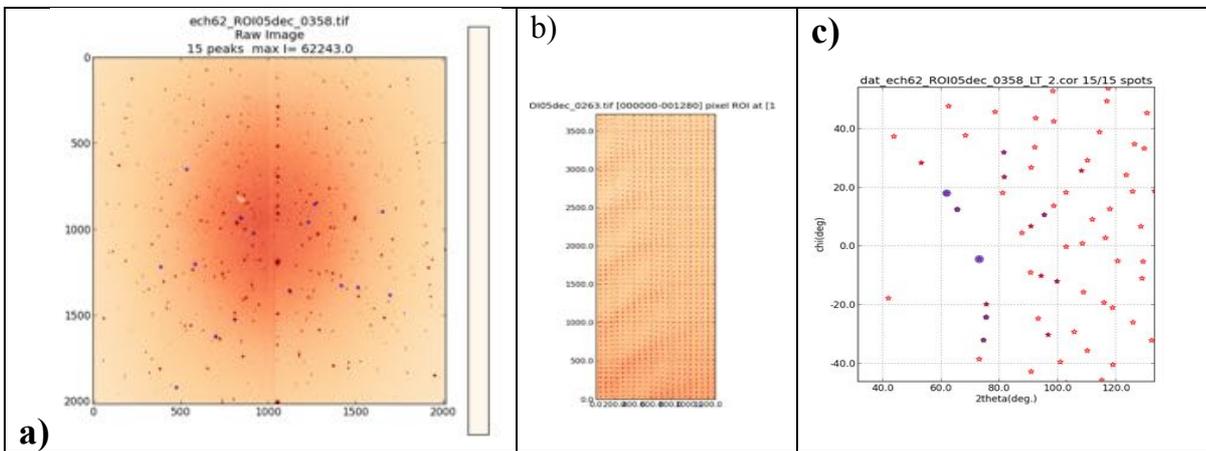


Figure 3: a) Laue pattern in an Al crystal. b) Mosaic image that shows that the variation of the intensity of a particular peak also follows the alternation of the lamellae. c) Best fit of the selected peaks (blue). The high-intensity (222) peak is close to the normal to the sample plane ( $2\theta=80\text{deg}$ ;  $\chi=0\text{ deg}$ ).

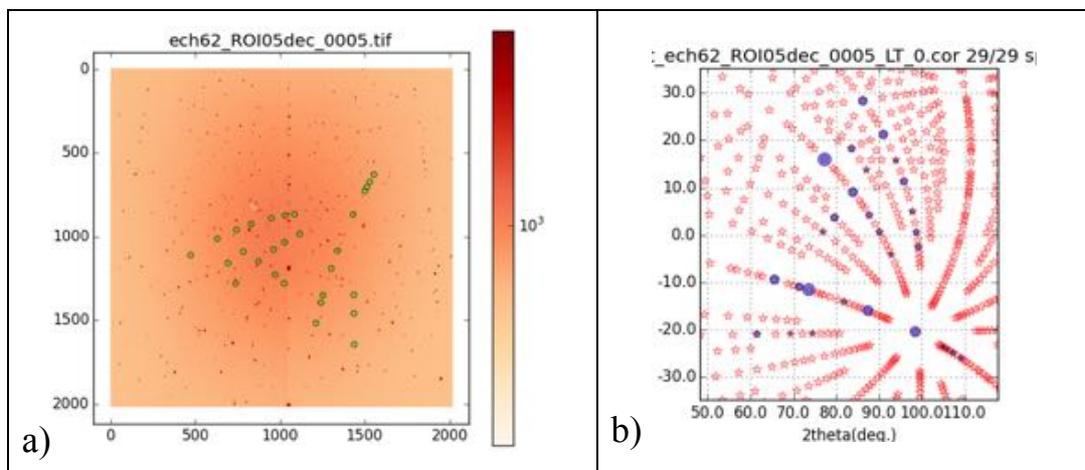


Figure 4: a) Laue pattern in an  $\text{Al}_2\text{Cu}$  crystal. b) Best fit of selected peaks (blue). The (100) peak is clearly visible.

In addition to the main problem (link between crystal orientation and microstructural features), various questions will be tentatively addressed:

**1-**Is there a variation of the orientation of the lamellae during growth? **2-**In a given eutectic grain, all the lamellae of one phase are known to originate from a single crystal seed. We have to check, however, if there is, as is often suspected, a progressive rotation, up to a few degrees, of the crystal lattice of the crystals across a eutectic grain. **3-**Diffraction peaks are often not circular (Fig. 5). This feature can evolve from one interphase boundary to the other, inside a given lamella. A detailed interpretation of that is not straightforward.

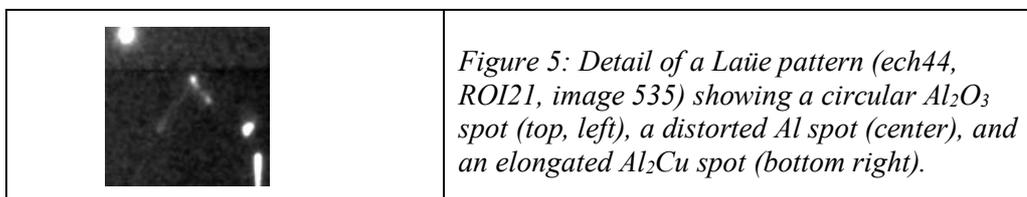


Figure 5: Detail of a Laue pattern (ech44, ROI21, image 535) showing a circular  $\text{Al}_2\text{O}_3$  spot (top, left), a distorted Al spot (center), and an elongated  $\text{Al}_2\text{Cu}$  spot (bottom right).

**- Justification and comments about the use of beam time: -**

The use of the synchrotron radiation was needed for nondestructive analysis through a sapphire plate. Micro-diffraction at ESRF in addition provides spatially resolved series of measurements, including crystal distortion, on a local scale with an unprecedented accuracy.

**- Conclusion: -**

In conclusion, our micro-diffraction measurements on Al- $\text{Al}_2\text{Cu}$  solidification microstructures through a sapphire plate have been successful. The use of a reference sample without sapphire was helpful for spatial calibration. Both Al and  $\text{Al}_2\text{Cu}$  crystals can be nicely indexed. The analyses will be performed more systematically. This requires not only the use of the LaueTools software, but also some image-analysis

development. The distortion of diffraction peaks seems to indicate small-scale strain: do mechanical stresses develop during growth at a small distance from the solid-liquid interface, or at a much lower temperature, far from the solidification front ? This question cannot be addressed ex situ. It would encourage, and motivate one to develop in situ micro-diffraction during solidification.